NSN 5961-01-321-8287

No Fiig: A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-321-8287 **Inclosure Material:** Ceramic or glass **Overall Length:** 2.375 inches **Terminal Length:** 3.000 inches **Overall Height:** 0.250 inches **Overall Width:** 0.500 inches **Mounting Method: Terminal Features Provided:** Burn in **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 12500.0 reverse voltage, peak **Current Rating Per Characteristic:** 500.00 milliamperes forward current, average absolute and 25.00 amperes forward current, average preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization: